MATERIAL INVESTIGATION AND ANALYSIS USING CHARACTERISTIC X-RAY

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The characteristic X-rays emitted from materials after gamma ray exposure was simulated and measured. A CdTe semiconductor detector and a 57 Co radiation source were used for energy spectroscopy. The types of materials could be identified by comparing the measured energy spectrum with the theoretical X-ray transition energy of the material. The sample composition was represented by the $K_{\alpha l}$ -line (Siegbahn notations), which has the highest intensity among the characteristic X-rays of each atom. The difference between the theoretic prediction and the experimental result of K-line measurement was < 0.61% even if the characteristic X-rays from several materials were measured simultaneously. 2D images of the mixed materials were acquired with very high selectivity.

KEYWORDS: XRF, Characteristic X-ray, CdTe

1. INTRODUCTION

X-ray fluorescence (XRF) analysis is a fast, reproducible, and non-destructive method that can be used to analyze multiple samples simultaneously. Therefore, it is one of the most common methods for obtaining qualitative and semi-quantitative information of the elements in a mixed sample. [1-2]

A vacancy is created when a photon of incoming radiation is absorbed completely by an atom, an electron in the inner shell is ejected from the atom, and the atom is left in an excited state. For stabilization, an electron in an outer shell falls into the vacancy and the difference in the energy status between the outer and the inner shell is converted to an Auger electron or a characteristic X-ray [2] (cf. Fig. 1). The XRF method measures the energy of the characteristic X-ray depending on the atomic number of the exposed material.

This study examined single and multiple materials by XRF, and the 2D distributions of the materials were obtained based on the XRF analysis.

2. MATERIALS AND METHODS

2.1 Semiconductor detector

XRF requires a detector with high energy resolution

to accurately analyze a mixed material. Therefore, a CdTe detector, which can measure a high resolution energy spectrum without a bulky cooling system for room temperature operation, was chosen for the XRF measurements [3-6]. The detector (XR-100T-CdTe) and accessories (PX4: Digital Pulse processor, MCA, and Power Supply) were obtained from AMPTEK.

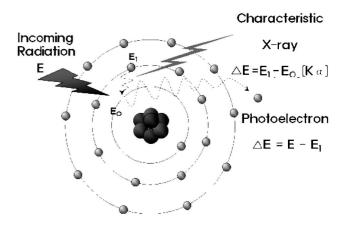


Fig. 1. The Process of the Characteristic X-ray Emission



Fig. 2.The Simulation Plot using MCNP

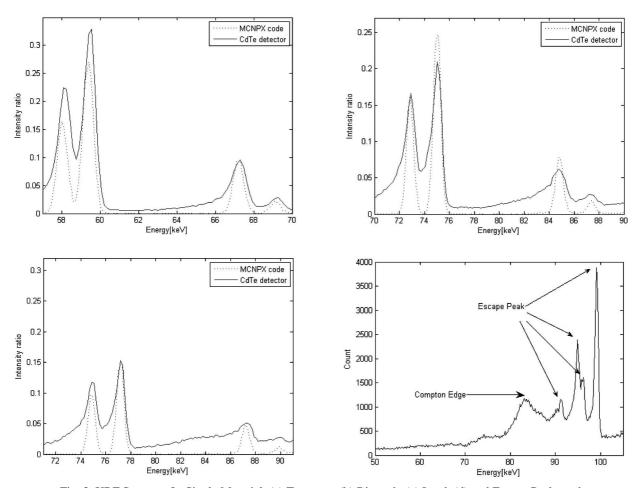


Fig. 3. XRF Spectra of a Single Material: (a) Tungsten, (b) Bismuth, (c) Lead, (d) and Escape Peaks and Compton Edge in a CdTe Detector

2.2 Isotope

Photoelectric absorption can occur only if the photon energy is equal to or greater than the binding energy of the electron. XRF shows its maximum intensity when the photon energy is just above the K-edge of the sample element. Therefore, ⁵⁷Co (Eckert & Zieger), whose radiation energy is 14keV (9.16%), 122keV (85.6%), and 136keV (10.68%), was used as the radiation source.

2.3 Geometrical positioning and energy spectrum

⁵⁷Co was placed between the CdTe detector and material (cf. Fig. 2). The radiation emitted directly from the ⁵⁷Co source was easily discriminated from the XRF radiation using the energy spectrum.

The FWHM parameters based on the observed energy broadening in the CdTe detector was applied to the MCNPX Monte Carlo simulation. The FWHMs of ⁵⁵Fe, ⁵⁷Co, ¹⁰⁹Cd, and ²⁴¹Am radiation sources were measured to produce the following empirical formula:

FWHM =
$$0.25433 + 1.3\sqrt{E + 2.4832E^2}$$
 [keV]. (1)

3. RESULTS

3.1 Single material

As shown in Figs. 3 and 4, the XRF spectrum of W, Pb, and Bi were measured. The peaks observed by the experiment and calculated by the simulation were

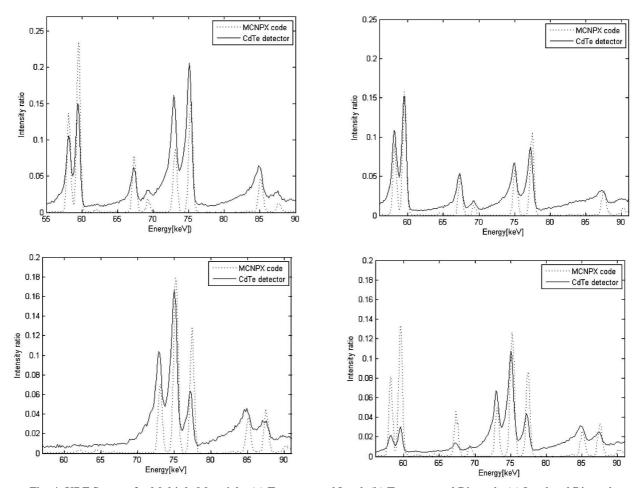


Fig. 4. XRF Spectra for Multiple Materials: (a) Tungsten and Lead, (b) Tungsten and Bismuth, (c) Lead and Bismuth, (d) Tungsten, and Lead and Bismuth

compared with the theoretical X-ray transition energies. These peaks were confirmed to be the $K_{\alpha l},\,K_{\alpha 2},\,K_{\beta l},$ and $K_{\beta 2}$ -lines allowed by the selection rules (cf. Table 1-8). The intensity of the $K_{\alpha l}$ -line was the highest because the electron transition from the L to K shell was the most probable process among the transitions. The characteristic X-ray peaks as well as the escape peaks and Compton scattering were observed, as shown in Fig. 3 (d). There was also spectrum distortion due to the tail effect in the CdTe semiconductor detector, which was caused by the poor charge collection and relatively small mobility lifetime of the holes [7-8]. The tail effect was more severe for the higher energy X-ray peaks.

The average difference between the theoretical and

simulation values for W was 0.044keV (0.07%) with a maximum difference of 0.088keV (0.15%). The average difference between the theoretical and simulation values for Pb was 0.079keV (0.1%) with a maximum difference of 0.135keV (0.18%). The average difference between the theoretical and simulation values for Bi was 0.097keV (0.12%) with a maximum difference of 0.147keV (0.12%).

The average difference between the theoretical and experimental values for W was 0.148keV (0.24%) with a maximum difference of 0.246keV (0.41%). The average difference between the theoretical and experimental values for Pb was 0.116keV (0.14%) with a maximum difference of 0.162keV (0.19%). The average difference

Table 1. Theoretical Transition Energies. (Unit, keV) [9-10]

Atom	$K_{\alpha l}$ -line	$K_{\alpha 2}$ -line	$K_{\beta I}$ -line	$K_{\beta 2}$ -line
74 W	59.318	57.981	67.245	69.102
82 Pb	74.970	72.806	84.940	87.362
83 Bi	77.108	74.816	87.351	89.849

Table 2. Energy Peak in Fig 3 (a) (Unit, keV)

Atom	Method	$K_{\alpha l}$ -line	$K_{\alpha 2}$ -line	$K_{\beta 1}$ -line	K _{β2} -line
74 W	CdTe	59.564	58.081	67.308	69.285
	MCNPX	59.406	58.006	67.305	69.105

Table 3. Energy Peak in Fig 3 (b) (Unit, keV)

Atom	Method	$K_{\alpha l}$ -line	K _{α2} -line	$K_{\beta 1}$ -line	K _{β2} -line
₈₂ Pb	CdTe	75.053	72.911	84.778	87.250
	MCNPX	75.105	72.805	84.804	87.404

Table 4. Energy Data in Fig 3 (c) (Unit, keV)

Atom	Method	$K_{\alpha l}$ -line	K _{α2} -line	$K_{\beta 1}$ -line	K _{β2} -line
₈₃ Bi	CdTe	77.196	74.888	87.250	90.053
	MCNPX	77.204	74.905	87.204	89.904

Table 5. Energy Peak in Fig 4 (a). (Unit, keV)

Atom	Method	$K_{\alpha l}$ -line	$K_{\alpha 2}$ -line	$K_{\beta 1}$ -line	K _{β2} -line
74 W	CdTe	59.399	58.081	67.308	69.450
	MCNPX	59.506	58.106	67.405	69.205
₈₂ Pb	CdTe	75.053	72.911	84.778	87.580
	MCNPX	75.305	73.105	85.204	87.804

between the theoretical and experimental values for Bi was 0.116keV (0.14%) with a maximum of 0.204keV (0.23%).

3.2. Complex materials

3.2.1. Two different materials

As shown in Figs. 4 (a) - (c), XRF was performed for a combination of two different materials among W, Pb, and Bi. When their atomic numbers were largely different, such as W/Pb or W/Bi, the energy peaks of each material could be clearly separated from each other. On the other hand, when the atomic number of the material was similar, such as Pb and Bi, the XRF peaks overlapped, preventing material analysis.

The mean difference between the theoretical and simulation values for W/Pb was 0.240keV (0.32%) with a maximum difference of 0.442keV (0.5%). The average difference between the theoretical and simulation values for W/Bi was 0.221keV (0.29%) with a maximum

difference of 0.396keV (0.51%). The average difference between the theoretical and simulation values for Pb/Bi was 0.267keV (0.33%) with a maximum difference of 0.555keV (0.61%).

The average difference between the theoretical and experimental values for W/Pb was 0.145keV (0.2%) with a maximum difference of 0.348keV (0.5%). The average difference between the theoretical and experimental values for W/Bi was 0.128keV (0.18%) with a maximum difference of 0.246keV (0.41%). The average difference between the theoretical and experimental values for Pb/Bi was 0.116keV (0.14%) with a maximum difference of 0.265keV (0.3%).

3.2.2. Three different materials

The average difference between the theoretical and simulation values for W was 0.169keV (0.27%) with a maximum difference of 0.288keV (0.48%). The average difference between the theoretical and simulation values

Table 6. Energy Peak in Fig 4 (b). (Unit, keV)

Atom	Method	$K_{\alpha l}$ -line	$K_{\alpha 2}$ -line	$K_{\beta 1}$ -line	$K_{\beta 2}$ -line
74 W	CdTe	59.564	58.081	67.308	69.121
	MCNPX	59.506	58.106	67.405	69.205
₈₃ Bi	CdTe	77.196	75.053	87.415	90.053
	MCNPX	77.504	75.005	87.504	90.304

Table 7. Energy Peak in Fig 4 (c). (Unit, keV)

Atom	Method	K _{\alpha1} -line	$K_{\alpha 2}$ -line	$K_{\beta 1}$ -line	K _{β2} -line
₈₂ Pb	CdTe	75.053(overlapped peak)	72.911	84.943	87.580
	MCNPX	75.205(overlapped peak)	73.105	85.004	87.504(overlapped peak)
₈₃ Bi	CdTe	77.196	75.053(overlapped peak)	87.086	89.888
	MCNPX	77.404	75.205(overlapped peak)	87.504(overlapped peak)	90.404

Table 8. Energy Peak in Fig 4 (d) (Unit, keV)

Atom	Method	K_{α^1} -line	$K_{\alpha 2}$ -line	K_{β^1} -line	K _{β2} -line
74 W	CdTe	59.564	58.246	67.308	69.285
	MCNPX	59.606	58.106	67.305	69.305
₈₂ Pb	CdTe	75.053(overlapped peak)	72.911	84.778	87.415(overlapped peak)
	MCNPX	75.205(overlapped peak)	73.105	85.004	87.604(overlapped peak)
₈₃ Bi	CdTe	77.196	75.053(overlapped peak)	87.415(overlapped peak)	90.218
	MCNPX	77.404	75.205(overlapped peak)	87.604(overlapped peak)	90.404

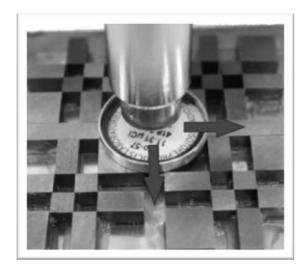
for Pb was 0.21keV (0.27%) with a maximum difference of 0.299keV (0.41%). The average difference between the theoretical and simulation values for Bi was 0.426keV (0.5%) with a maximum difference of 0.555keV (0.61%).

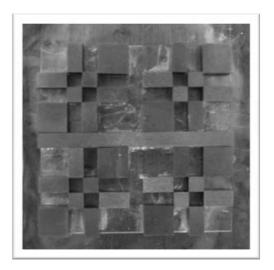
The average difference between the theoretical and experimental values for W was 0.189keV (0.31%) with a maximum difference of 0.265keV (0.45%). The average difference between the theoretical and experimental values for Pb was 0.101keV (0.13%) with a maximum difference OF 0.162keV (0.19%). The average difference between the theoretical and experimental values for bismuth was 0.229keV (0.26%) with a maximum difference of 0.369 keV (0.41%).

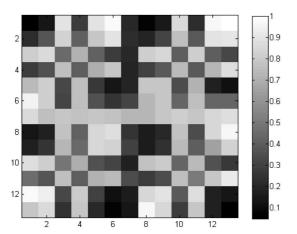
The overlapping of the simulation and experimental peaks increased with an increasing number of elements in the mixed material, and, hence, the spectral uncertainties also increased with an increasing number of elements. The difference in XRF intensity between the experiment and simulation was caused by a discrepancy between the experiment and simulation conditions, such as the amount, density, and location of each element.

3.3 Material distribution

2D images of mixed materials were obtained by measuring the $K_{\alpha l}$ -line intensity of each element. As shown in Fig. 5 (a), a detector and source scanned a mixed material in the orthogonal direction with a fixed timing step. The first material was patterned tungsten on top of a lead plate (cf. Fig. 5 (b)). The size of the entire pattern and that of the pattern unit was $6.5\times6.5\times0.5$ cm³ and $0.5\times0.5\times0.5$ cm³, respectively. As shown in Figs. 5 (c) and (d), the distributions of the two different







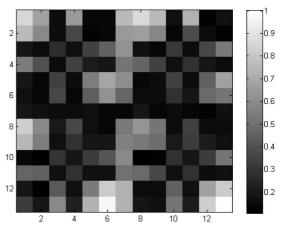
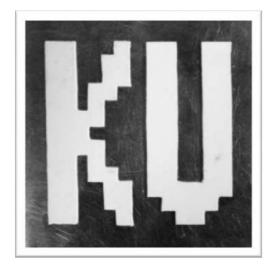


Fig. 5. Photographs of the Experiment and 2D XRF Images of a Mixed Material: (a) Detector and Source Movement, (b) Patterned Tungsten on a Lead Plate, (c) Relative Kα1-line Intensity of Tungsten, and (d) Relative Kα1-line Intensity of Lead



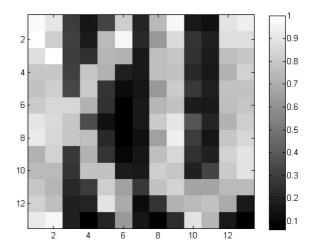


Fig. 6. Photograph and 2D XRF Image of Bi Characters on an Al plate: (a) Two Bi Characters on an Al Plate and (b) Relative Kal-line Intensity of Bi

materials were clearly separated from each other. Fig. 6 shows a photo and a 2D XRF image of a Bi character on an Al plate. While the distribution of Bi was clearly reconstructed, that of the Al plate could not be analyzed because, for light elements (Z<20), the dominant product of K shell ionization is Auger electrons rather than characteristic X-rays, and the Al transition energies are similar to the ⁵⁷Co radiation energy [2]. The scanning time for each step was 60 seconds, and the total scanning time was approximately 3 hours.

4. CONCLUSIONS

The XRF spectrum and distribution of mixed materials were obtained. The simulation and experimental results for the XRF spectrum were well matched with the theoretical values (<0.61%). In the case of a mixed material, some of the XRF peaks were overlapped by energy broadening and a tail effect, which prevented spectral analysis. The 2D XRF distributions were obtained by scanning a detector and a source over the mixed materials. A 2D image of the tungsten patterns on a lead plate was clearly reconstructed. A Bi character was highly discernable on an Al plate. However, the XRF radiation from the Al plate could not be distinguished from the radiation coming directly from the ⁵⁷Co source.

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